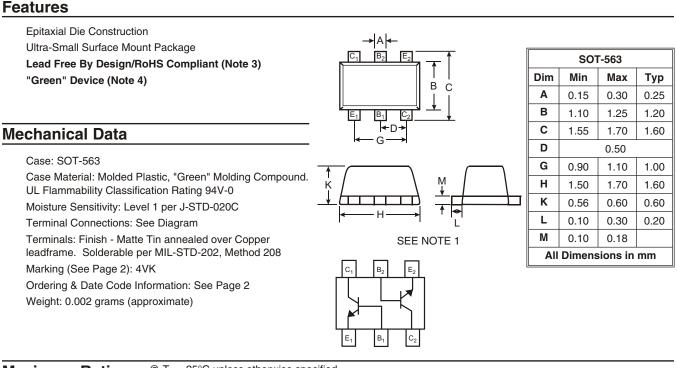




BC847BVC

NPN DUAL SMALL SIGNAL SURFACE MOUNT TRANSISTOR



Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	50	V	
Collector-Emitter Voltage	V _{CEO}	45	V	
Emitter-Base Voltage	V _{EBO}	6.0	V	
Collector Current	Ι _C	100	mA	
Power Dissipation (Note 2)	Pd	150	mW	
Thermal Resistance, Junction to Ambient (Note 2)	R _{JA}	833	°C/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C	

Notes: 1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180 rotated, or mixed (both ways).

 Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

3. No purposefully added lead.

4. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php



Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Min Typ Max Unit		Test Condition		
Collector-Base Breakdown Voltage	(Note 5)	V _{(BR)CBO}	50	_	_	V	I _C = 10 A, I _B = 0
Collector-Emitter Breakdown Voltage	(Note 5)	V _{(BR)CEO}	45	_	_	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage (Note 5)		V _{(BR)EBO}	6 — V IE=		$I_E = 1$ A, $I_C = 0$		
DC Current Gain	(Note 5)	h _{FE}	200	290	450	_	$V_{CE} = 5.0V, I_C = 2.0mA$
Collector-Emitter Saturation Voltage (Note 5		V _{CE(SAT)}	_	_	100 300	mV	$I_{C} = 10mA, I_{B} = 0.5mA$ $I_{C} = 100mA, I_{B} = 5.0mA$
Base-Emitter Saturation Voltage (Note 5)		VBE(SAT)	_	700 900	_	mV	$I_{C} = 10mA, I_{B} = 0.5mA$ $I_{C} = 100mA, I_{B} = 5.0mA$
Base-Emitter Voltage (Note 5)		V _{BE}	580 —	660	700 770	mV	
Collector-Emitter Cutoff Current	(Note 5)	I _{CBO} I _{CBO}	_		15 5.0	nA μA	$\label{eq:VCB} \begin{array}{l} V_{CB}=30V\\ V_{CB}=30V, \ T_{A}=150^{\circ}C \end{array}$
Gain Bandwidth Product		f⊤	100	_	_	MHz	$V_{CE} = 5.0V, I_{C} = 10mA, f = 100MHz$
Output Capacitance		C _{OBO}	—	_	4.5	pF	V _{CB} = 10V, f = 1.0MHz
Noise Figure		NF	_	_	10	dB	V _{CE} = 5V, R _S = 2.0k f = 1.0kHz, BW = 200Hz

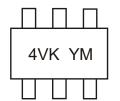
Ordering Information (Note 6)

Device	Packaging	Shipping
BC847BVC-7	SOT-563	3000/Tape & Reel

Notes: 5. Short duration pulse test used to minimize self-heating effect.

6. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

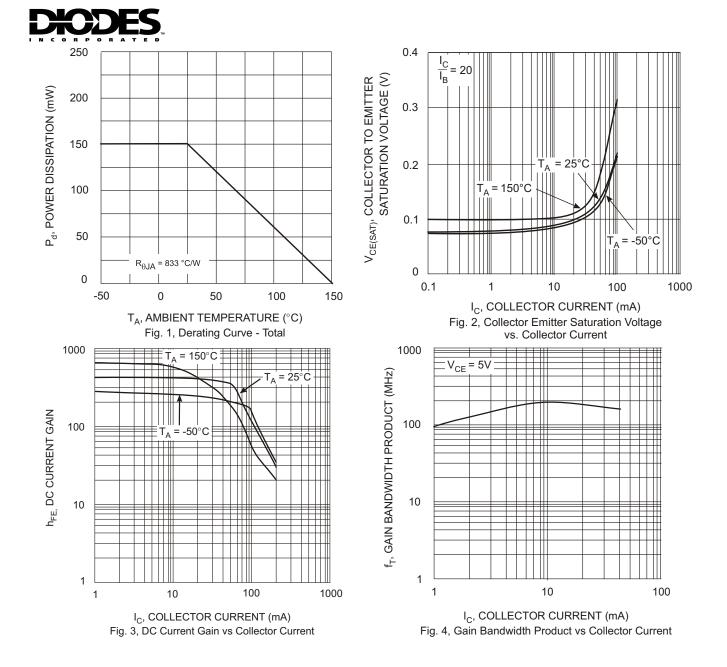
Marking Information



4VK = Product Type Marking Code YM = Date Code Marking Y = Year (ex: P = 2003) M = Month (ex: 9 = September)

Date Code Key

Year	2005	:	2006	2007		2008	200	9	2010	2011		2012
Code	S		Т	U		V	W		Х	Y		Z
Month	Jan	Feb	March	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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